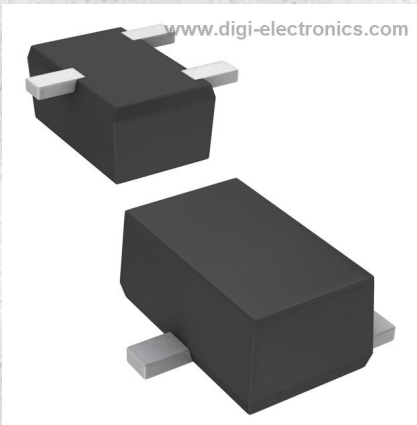


2SC39380RL Datasheet



<https://www.DiGi-Electronics.com>

| | |
|------------------------------|---|
| DiGi Electronics Part Number | 2SC39380RL-DG |
| Manufacturer | Panasonic Electronic Components |
| Manufacturer Product Number | 2SC39380RL |
| Description | TRANS NPN 40V 0.1A SMini3 |
| Detailed Description | Bipolar (BJT) Transistor NPN 40 V 100 mA 450MHz 1 50 mW Surface Mount SMini3-G1 |



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.

Purchase and inquiry

Manufacturer Product Number:

25C39380RL

Series:

-

Transistor Type:

NPN

Voltage - Collector Emitter Breakdown (Max):

40 V

Current - Collector Cutoff (Max):

100nA (ICBO)

Power - Max:

150 mW

Operating Temperature:

150°C (TJ)

Package / Case:

SC-70, SOT-323

Base Product Number:

25C3938

Manufacturer:

Panasonic Electronic Components

Product Status:

Obsolete

Current - Collector (Ic) (Max):

100 mA

Vce Saturation (Max) @ Ib, Ic:

250mV @ 1mA, 10mA

DC Current Gain (hFE) (Min) @ Ic, Vce:

90 @ 10mA, 1V

Frequency - Transition:

450MHz

Mounting Type:

Surface Mount

Supplier Device Package:

SMini3-G1

Environmental & Export classification

Moisture Sensitivity Level (MSL):

1 (Unlimited)

HTSUS:

8541.21.0075

ECCN:

EAR99

2SC3938

Silicon NPN epitaxial planar type

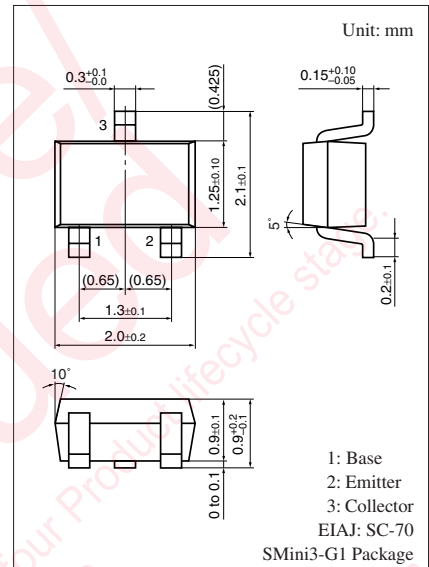
For high-speed switching

■ Features

- Low collector-emitter saturation voltage $V_{CE(sat)}$
- S-Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing

■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

| Parameter | Symbol | Rating | Unit |
|---------------------------------------|-----------|-------------|------------------|
| Collector-base voltage (Emitter open) | V_{CBO} | 40 | V |
| Collector-emitter voltage (E-B short) | V_{CES} | 40 | V |
| Emitter-base voltage (Collector open) | V_{EBO} | 5 | V |
| Collector current | I_C | 100 | mA |
| Peak collector current | I_{CP} | 300 | mA |
| Collector power dissipation | P_C | 150 | mW |
| Junction temperature | T_j | 150 | $^\circ\text{C}$ |
| Storage temperature | T_{stg} | -55 to +150 | $^\circ\text{C}$ |



Marking Symbol: 2Y

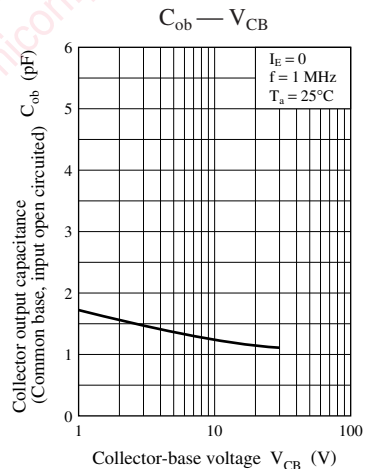
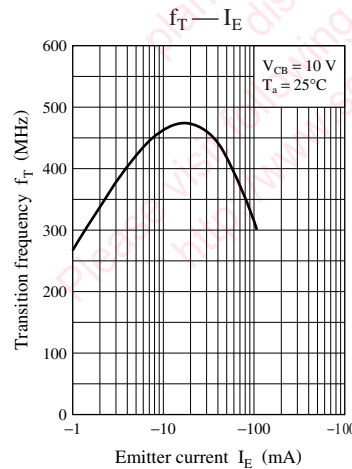
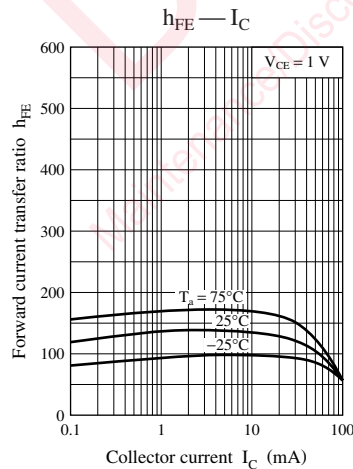
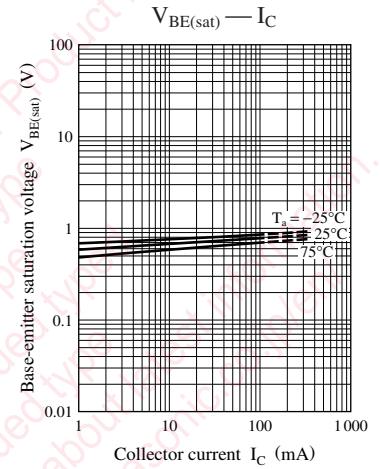
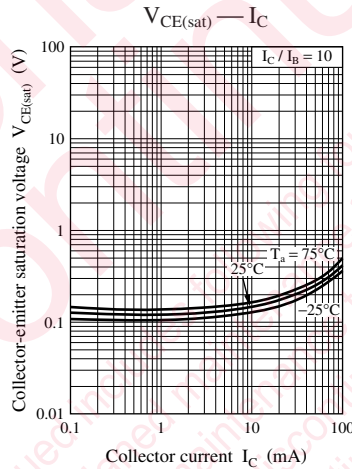
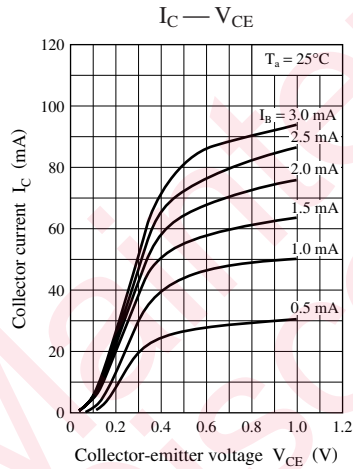
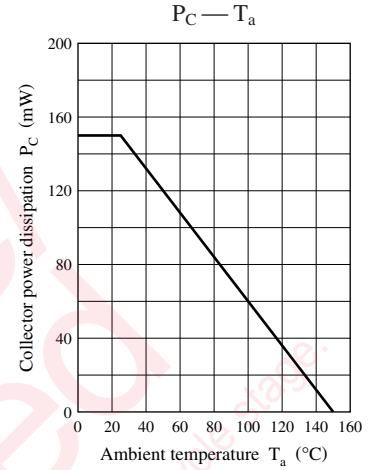
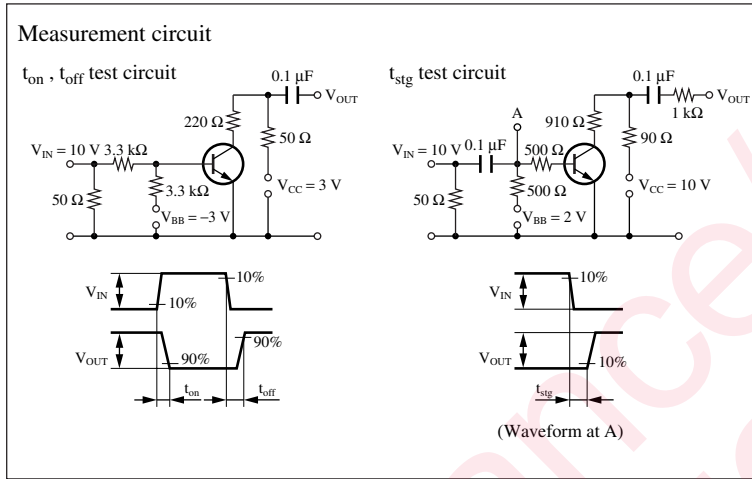
■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|--|---------------|---|-----|------|------|---------------|
| Collector-base cutoff current (Emitter open) | I_{CBO} | $V_{CB} = 40\text{ V}, I_E = 0$ | | | 0.1 | μA |
| Emitter-base cutoff current (Collector open) | I_{EBO} | $V_{EB} = 4\text{ V}, I_C = 0$ | | | 0.1 | μA |
| Forward current transfer ratio * | h_{FE} | $V_{CE} = 1\text{ V}, I_C = 10\text{ mA}$ | 60 | | 200 | — |
| Collector-emitter saturation voltage | $V_{CE(sat)}$ | $I_C = 10\text{ mA}, I_B = 1\text{ mA}$ | | 0.17 | 0.25 | V |
| Base-emitter saturation voltage | $V_{BE(sat)}$ | $I_C = 10\text{ mA}, I_B = 1\text{ mA}$ | | | 1 | V |
| Transition frequency | f_T | $V_{CB} = 10\text{ V}, I_E = -10\text{ mA}, f = 200\text{ MHz}$ | | 450 | | MHz |
| Collector output capacitance (Common base, input open circuited) | C_{ob} | $V_{CB} = 10\text{ V}, I_E = 0, f = 1\text{ MHz}$ | | 2 | 6 | pF |
| Turn-on time | t_{on} | Refer to the measurement circuit | | 17 | | ns |
| Turn-off time | t_{off} | | | 17 | | ns |
| Storage time | t_{stg} | | | 10 | | ns |

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. *: Rank classification

| Rank | Q | R |
|----------|-----------|-----------|
| h_{FE} | 60 to 120 | 90 to 200 |



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